

February 2013

FAN4931 Ultra-Low Cost, Rail-to-Rail I/O, CMOS Amplifier

Features

- 200 μA Supply Current per Amplifier
- 3.7 MHz Bandwidth
- Output Swing to within 10 mV of Either Rail
- Input Voltage Range Exceeds the Rails
- 3 V/µs Slew Rate
- 25 nV/√Hz Input Voltage Noise
- FAN4931 Competes with LMV931; Available in SC70-5 Package
- Fully Specified at +2.7 V and +5 V Supplies

Applications

- Motor Control
- Portable / Battery-Powered Applications
- PCMCIA, USB
- Mobile Communications, Cellular Phones, Pagers
- Notebooks and PDAs
- Sensor Interface
- A/D Buffer
- Active Filters
- Signal Conditioning
- Portable Test Instruments

Description

FAN4931 is an ultra-low cost voltage feedback amplifier with CMOS inputs that consumes only 200 μ A of supply current, while providing ±33 mA of output short-circuit current. This amplifier is designed to operate from 2.5 V to 5 V supplies. The common-mode voltage range extends beyond the negative and positive rails.

The FAN4931 is designed on a CMOS process and provides 3.7 MHz of bandwidth and 3 V / μ s of slew rate at a supply voltage of 5 V. This amplifier operates and is reliable over a wide temperature range -40°C to +125°C. The combination of extended temperature operation, low power, rail-to-rail performance, low voltage operation,and tiny package optimizes this amplifier for use in many industrial, general purpose and battery powered applications.

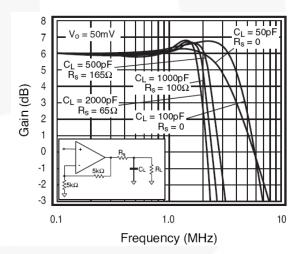


Figure 1. Frequency vs. Gain

Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method	
FAN4931IP5X	-40 to +125°C	5-Lead SC70 Package	Tape and Reel (3000)	

Typical Application

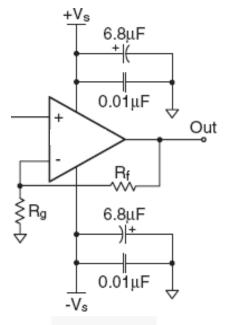


Figure 2. Typical Application

Pin Configurations

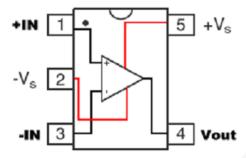


Figure 3. Pin Assignments

Pin Assignments

Pin#	Name	Description
1	+IN	Positive Input
2	-Vs	Negative Supply
3	-IN	Negative Input
4	V_{OUT}	Output
5	+V _S	Positive Supply

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Functional operation under any of these conditions is NOT implied. Performance and reliability are guaranteed only if operating conditions are not exceeded.

Symbol	Parameter			Max.	Unit
V _{CC}	Supply Voltage		0	6	V
V_{IN}	Input Voltage Range	Input Voltage Range			V
TJ	Junction Temperature		+150	°C	
T _{STG}	Storage Temperature	-65	+150	°C	
TL	Lead Soldering, 10 Seconds		+300	°C	
Θ_{JA}	Thermal Resistance ⁽¹⁾		331	°C/W	
ESD	Flacture testic Discharge Constility	Human Body Model, JESD22-A114		5	147
EOD	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101		2	kV

Note:

1. Package thermal resistance JEDEC standard, multi-layer test boards, still air.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
+Vs	Supply Voltage	2.30	5.25	V
T _A	Operating Temperature Range	-40	+125	°C

Electrical Specifications at +2.7V

 $V_S \text{=+2.7 V}, \, G \text{=-2}, \, R_L \text{=-10 k}\Omega$ to $V_S / 2, \, R_F \text{=-5 k}\Omega;$ unless otherwise noted.

Symbol	Parameter Conditions		Min.	Тур.	Max.	Units	
Frequency Do	omain Response					•	
UGBW	2dD Doordy sidth	G=+1		4.0		MHz	
BWss	-3dB Bandwidth			2.5		MHz	
GBWP	Gain Bandwidth Product			4		MHz	
Time Domain	Response						
t _R , f _F	Rise and Fall Time	V _O =1.0 V Step		300		ns	
os	Overshoot	V _O =1.0 V Step		5		%	
SR	Slew Rate	V ₀ =3 V Step, G=-1		3		V/µs	
Distortion and	Noise Response						
HD2	2nd Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		-66		dBc	
HD3	3rd Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		-67		dBc	
THD	Total Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		0.1		%	
en	Input Voltage Noise			26		nV/√Hz	
DC Performan	nce						
V _{IO}	Input Offset Voltage ⁽²⁾		-6	0	+6	mV	
dV_{IO}	Average Drift			2.1		μV/°C	
I _{bn}	Input Bias Current			5		pA	
PSRR	Power Supply Rejection Ratio ⁽²⁾	DC	50	73		dB	
A _{OL}	Open-Loop Gain	DC		98		dB	
Is	Supply Current per Amplifier ⁽²⁾			200	300	μA	
Input Charact	eristics						
R _{IN}	Input Resistance			10		GΩ	
C _{IN}	Input Capacitance			1.4		pF	
CMIR	Input Common Mode Voltage Range			-0.3 to 2.8		V	
CMRR	Common Mode Rejection Ratio ⁽²⁾	DC, V _{CM} =OV to 2.2 V	50	65		dB	
Output Chara	cteristics						
	Output Vallage Suine(2)	R_L =10 kΩ to V_S /2	0.03	0.01 to 2.69	2.65		
Vo	Output Voltage Swing ⁽²⁾	R_L =1 kΩ to V_S /2		0.05 to 2.55		V	
Isc	Short-Circuit Output Current			+34/-12		mA	
Vs	Power Supply Operating Range			2.5 to 5.5		V	

Note:

2. 100% tested at T_A =25°C.

Electrical Specifications at +5V

 $V_S \!\!=\!\! +5$ V, G=2, $R_L \!\!=\!\! 10$ $k\Omega$ to $V_S/2,$ $R_F \!\!=\! 5$ $k\Omega;$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Frequency Do	omain Response	•	•	•		•
UGBW		G=+1		3.7		MHz
BWss	-3dB Bandwidth			2.3		MHz
GBWP	Gain Bandwidth Product			3.7		MHz
Time Domain	Response					
t _R , f _F	Rise and Fall Time	V _O =1.0 V Step		300		ns
os	Overshoot	V _O =1.0 V Step		5		%
SR	Slew Rate	V _O =3 V Step, G=-1		3		V/µs
Distortion and	Noise Response					•
HD2	2nd Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		-80		dBc
HD3	3rd Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		-80		dBc
THD	Total Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		0.02		%
e _n	Input Voltage Noise			25		nV/√Hz
DC Performar	nce	1				
V _{IO}	Input Offset Voltage ⁽³⁾		-8	0	+8	mV
dV _{IO}	Average Drift			2.9		μV/°C
I _{bn}	Input Bias Current			5		pА
PSRR	Power Supply Rejection Ratio ⁽³⁾	DC	50	73		dB
A _{OL}	Open-Loop Gain	DC		102		dB
Is	Supply Current per Amplifier ⁽³⁾			200	300	μA
Input Charact	eristics					
R _{IN}	Input Resistance			10		GΩ
C _{IN}	Input Capacitance			1.2		pF
CMIR	Input Common Mode Voltage Range	Typical		-0.3 to 5.1		V
CMRR	Common Mode Rejection Ratio ⁽³⁾	DC, V _{CM} =0 V to V _S	58	73		dB
Output Chara	cteristics			•		
Output Valtage Cuin (3)		R_L =10 k Ω to V_S /2	0.03	0.01 to 4.99	4.95	V
Vo	Output Voltage Swing ⁽³⁾	R_L =1 k Ω to V_S /2		0.1 to 4.9		V
I _{SC}	Short-Circuit Output Current			±33		mA
Vs	Power Supply Operating Range			2.5 to 5.5		V

Note:

3. 100% tested at T_A =25°C.

Typical Performance Characteristics

 V_S =+2.7, G=2, R_L =10 k Ω to V_S /2, R_F =5 k Ω ; unless otherwise noted.

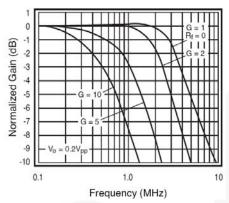


Figure 4. Non-Inverting Frequency Response (+5)

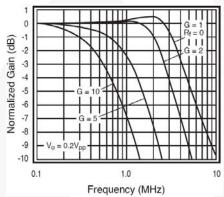


Figure 6. Non-Inverting Frequency Response

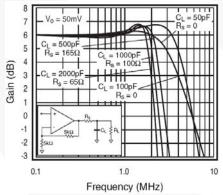


Figure 8. Frequency Response vs. C_L

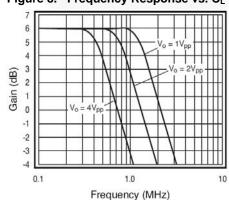


Figure 10. Large Signal Frequency Response (+5 V)

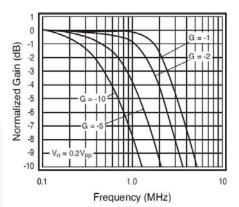


Figure 5. Inverting Frequency Response (+5 V)

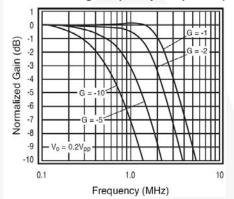


Figure 7. Inverting Frequency Response

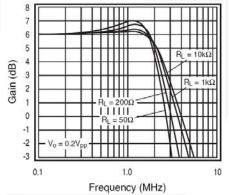


Figure 9. Frequency Response vs. RL

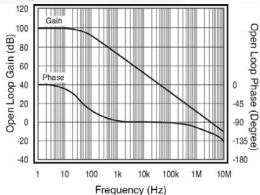


Figure 11. Open-Loop Gain and Phase vs. Frequency

Typical Performance Characteristic

 $V_S \!\!=\!\! +2.7,\, G \!\!=\!\! 2,\, R_L \!\!=\!\! 10~k\Omega$ to $V_S/2,\, R_F \!\!=\!\! 5~k\Omega;$ unless otherwise noted.

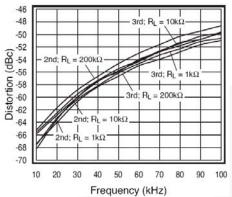


Figure 12. 2nd and 3rd Harmonic Distortion

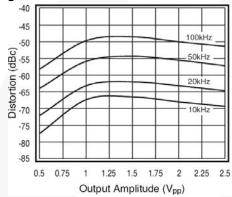
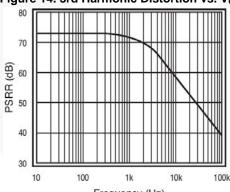


Figure 14. 3rd Harmonic Distortion vs. Vo



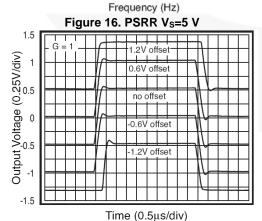


Figure 18. Pulse Response vs. Common-Mode Voltage

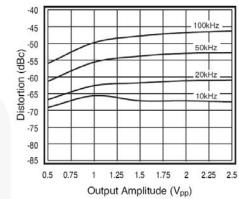


Figure 13. 2nd Harmonic Distortion vs. Vo

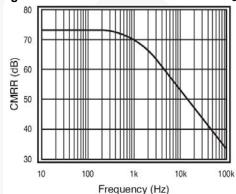


Figure 15. CMRR V_s=5 V

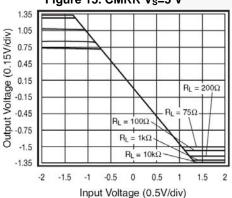


Figure 17. Output Swing vs. Load

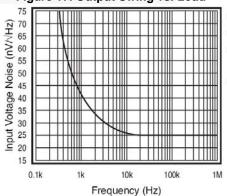


Figure 19. Input Voltage Noise

Application Information

General Description

The FAN4931 amplifier is a single-supply, general-purpose, voltage-feedback amplifier, fabricated on a bi-CMOS process. It features a rail-to-rail input and output and is unity gain stable. The typical non-inverting circuit schematic is shown in Figure 20.

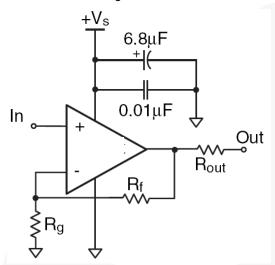


Figure 20. Typical Non-Inverting Configuration

Input Common-Mode Voltage

The common-mode input range extends to 300 mV below ground and to 100 mV above $V_{\rm S}$ in single-supply operation. Exceeding these values does not cause phase reversal; however, if the input voltage exceeds the rails by more than 0.5 V, the input ESD devices begin to conduct. The output stays at the rail during this overdrive condition. If the absolute maximum input $V_{\rm IN}$ (700 mV beyond either rail) is exceeded, externally limit the input current to ± 5 mA, as shown in Figure 21.

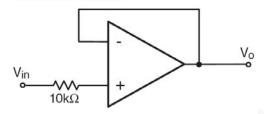


Figure 21. Circuit for Input Current Protection

Power Dissipation

The maximum internal power dissipation allowed is directly related to the maximum junction temperature. If the maximum junction temperature exceeds 150°C, performance degradation occurs. If the maximum junction temperature exceeds 150°C for an extended time, device failure may occur.

Overdrive Recovery

Overdrive of an amplifier occurs when the output and/or input ranges are exceeded. The recovery time varies based on whether the input or output is overdriven and by how much the range is exceeded. The FAN4931 typically recovers in less than 500 ns from an overdrive condition. Figure 22 shows the FAN4931 amplifier in an overdriven condition.

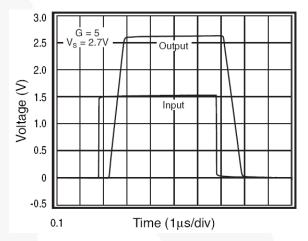


Figure 22. Overdrive Recovery

Driving Capacitive Loads

Figure 8 illustrates the response of the amplifier. A small series resistance ($R_{\rm S}$) at the output, illustrated in Figure 23, improves stability and settling performance. $R_{\rm S}$ values in Figure 8 were chosen to achieve maximum bandwidth with less than 2 dB of peaking. For maximum flatness, use a larger $R_{\rm S}$. Capacitive loads larger than 500 pF require the use of $R_{\rm S}$.

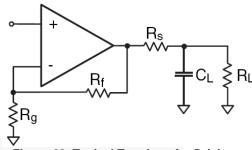


Figure 23. Typical Topology for Driving a Capacitive Load

Driving a capacitive load introduces phase-lag into the output signal, which reduces phase margin in the amplifier. The unity gain follower is the most sensitive configuration. In a unity gain follower configuration, the amplifier requires a 300 Ω -series resistor to drive a 100 pF load.

Layout Considerations

General layout and supply bypassing play major roles in high-frequency performance. Fairchild evaluation boards help guide high-frequency layout and aid in device testing and characterization. Follow the steps below as a basis for high-frequency layout:

Include 6.8 µF and 0.01 µF ceramic capacitors.

Place the 6.8 μF capacitor within 0.75 inches of the power pin.

Place the $0.01\,\mu\text{F}$ capacitor within 0.1 inches of the power pin.

Remove the ground plane under and around the part, especially near the input and output pins, to reduce parasitic capacitance.

Minimize all trace lengths to reduce series inductances.

Refer to the evaluation board layouts shown in Figure 24-Figure 26 for more information.

When evaluating only one channel, complete the following on the unused channel:

Ground the non-inverting input.

Short the output to the inverting input.

Evaluation Board Information

The following evaluation board is available to aid in the testing and layout of this device.

Evaluation Board	Description	Products	
FAN4931-011	Single-Channel, Dual-Supply, 5 -Lead SC70	FAN4931IP5X	

Evaluation board schematics are shown in Figure 24; layouts are shown in Figure 25-Figure 26.

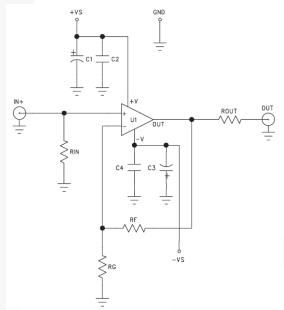


Figure 24. Evaluation Board Schematic

Board Layout Information

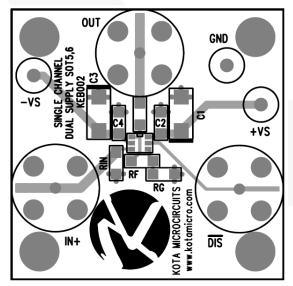


Figure 25. Top Side

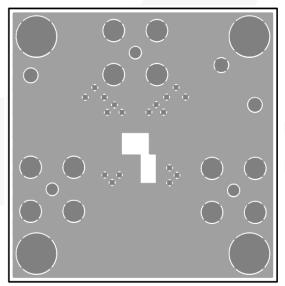


Figure 26. Bottom Side

Physical Dimensions

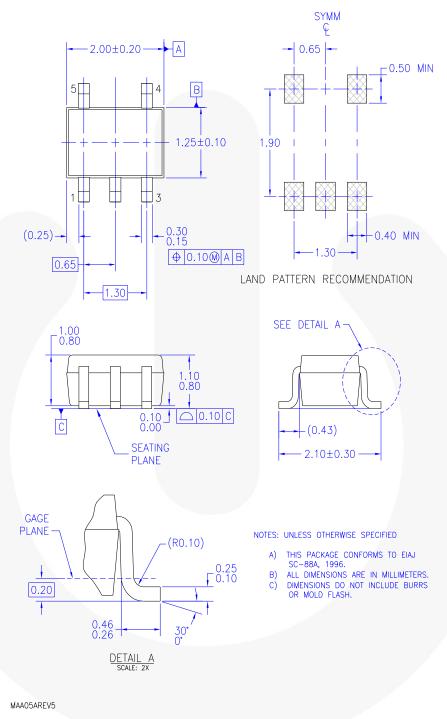


Figure 27. 5-Lead SC70 Package

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